



## **Product Summary**

BV <sub>DSS</sub>	Rds(on)	Ι <sub>D</sub> Τ <sub>A</sub> = +25°C
-100V	4.2Ω @ V <sub>GS</sub> = -10V	-0.27A
-100V	5.0Ω @ V <sub>GS</sub> = -4.0V	-0.24A

# **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

#### **100V P-CHANNEL ENHANCEMENT MODE MOSFET**

## **Features and Benefits**

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package ESD Protected up to 2kV (HBM)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Qsuffix) part. A listing can be found at https://www.diodes.com/products/automotive/automotive/

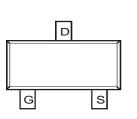
https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/guality/product-definitions/

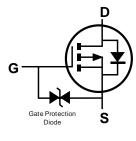
## **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (@3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Top View

**Pin Configuration** 



Equivalent Circuit

#### Ordering Information (Note 4)

Part Number	Paakaga	Pa	cking
Part Number	Package	Qty.	Carrier
DMP10H4D2S-7	SOT23 (Standard)	3,000	Tape & Reel
DMP10H4D2S-13	SOT23 (Standard)	10,000	Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Notes:

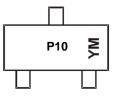
SOT23 (Standard)

Top View





# **Marking Information**



P10 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: I = 2021) M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	2015		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	С			J	K	L	М	Ν	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-100	V		
Gate-Source Voltage	Vgss	±20	V		
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	ID	-0.27 -0.21	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle ≤1%)	ldм	-1.0	А		
Maximum Body Diode Continuous Current (Note 6)			ls	-0.27	A

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation		(Note 5)		0.38	W
		(Note 6)	PD	0.44	vv
Thermal Resistance, Junction to Ambient Steady		(Note 5)	R <sub>0JA</sub>	333	
Thermal Resistance, Junction to Ambient State		(Note 6)	Reja	282	°C/W
Thermal Resistance, Junction to Case	(Note 6)	Rejc	115		
Operating and Storage Temperature Range			TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.



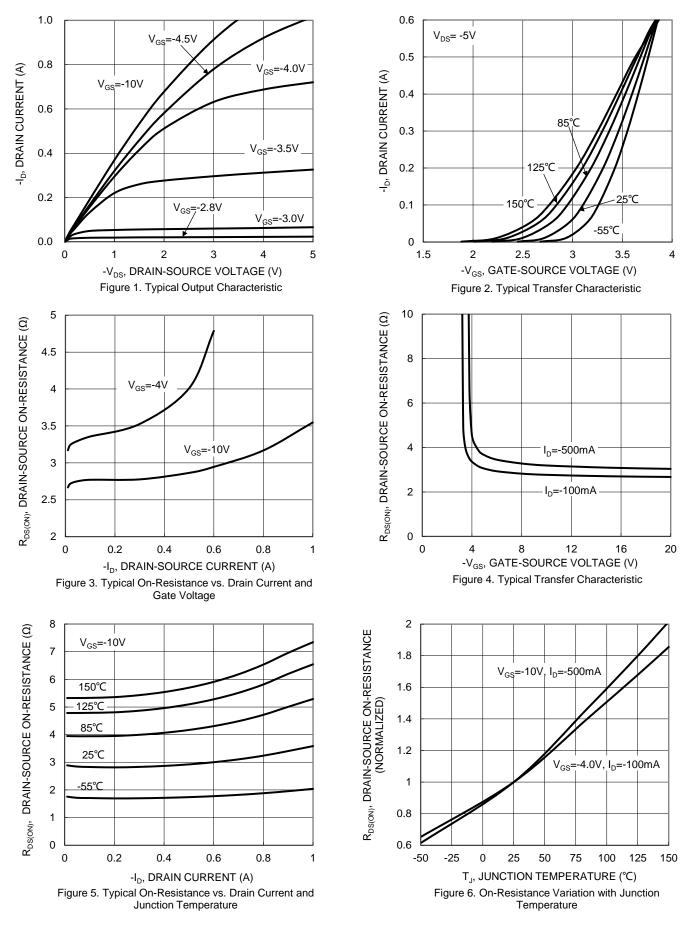
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-100	—	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS			-1	μA	$V_{DS} = -100V, V_{GS} = 0V$	
Gate-Body Leakage	IGSS		—	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-1.0	-2.3	-3.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Pro/onii		2.8	4.2	Ω	V <sub>GS</sub> = -10V, I <sub>D</sub> = -0.5A	
Static Drain-Source On-Resistance	RDS(ON)		3.2	5.0	12	$V_{GS} = -4.0V, I_D = -0.1A$	
Diode Forward Voltage	V <sub>SD</sub>		-0.82	-1.3	V	$V_{GS} = 0V, I_{S} = -0.2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		87	_			
Output Capacitance	Coss	_	5.6	_	pF	Vps = -25V, Vgs = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	2.9	—		T = 1.0MHZ	
Gate Resistance	Rg		15.3	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	
Total Gate Charge	Qg		1.8			N/ 001/11/ 401/	
Gate-Source Charge	Qgs		0.3		nC	Vps = -80V, Vgs = -10V, lp = -0.5A	
Gate-Drain Charge	Q <sub>gd</sub>		0.5	_	1	ID = -0.5A	
Turn-On Delay Time	tD(ON)		3.3				
Turn-On Rise Time	tR	_	2.6	—	ns	VDS = -50V, ID = -0.5A,	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		8.4	_	115	$V_{GS}$ = -10V, $R_G$ = 10 $\Omega$	
Turn-Off Fall Time	tF		4.9				
Reverse Recovery Time	trr	_	17.8		ns	V <sub>R</sub> = -100V, I <sub>F</sub> = -1.0A,	
Reverse Recovery Charge	Qrr		24.8		nC	di/dt = 100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:



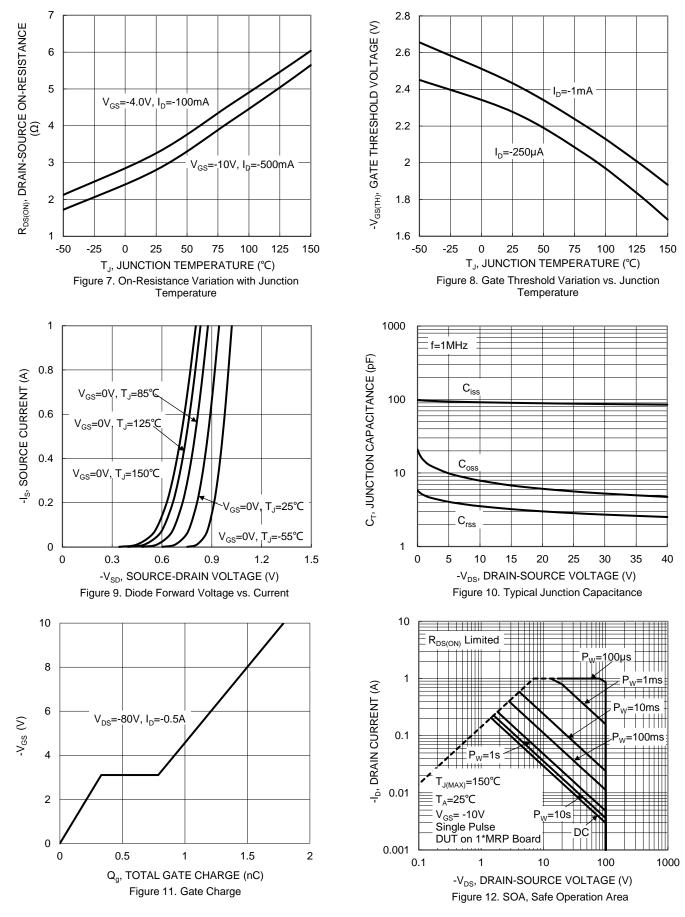
## DMP10H4D2S



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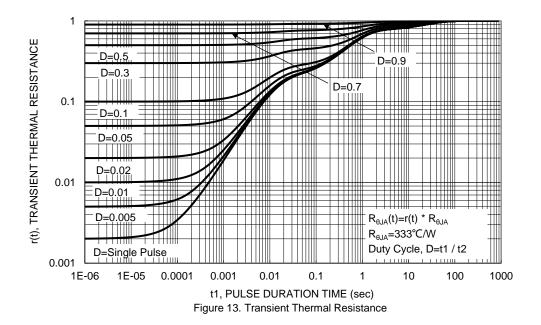


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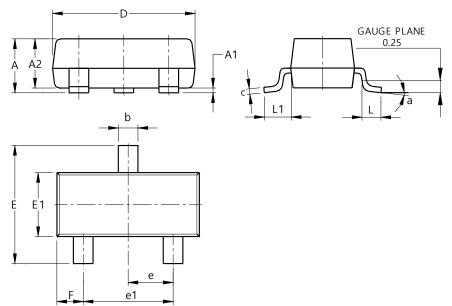






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



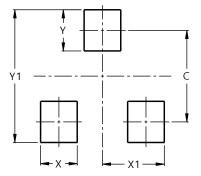
S	SOT23 (Standard)						
Dim	Min	Max	Тур				
Α	0.90	1.15	1.025				
A1	0.00	0.10	0.05				
A2	0.85	1.10	0.975				
b	0.30	0.51	0.40				
c	0.080	0.202	0.11				
D	2.80	3.00	2.90				
Е	2.25	2.55	2.40				
E1	1.20	1.40	1.30				
е	0.89	1.03	0.915				
e1	1.78	2.05	1.83				
F	0.40	0.60	0.535				
L1	0.45	0.61	0.55				
L	0.25	0.55	0.40				
а	0°	8°					
All	Dimens	ions in	mm				

# SOT23 (Standard)

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Standard)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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